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BLF184XR; BLF184XRS

Power LDMOS transistor Rev. 4 — 1 September 2015

AMPLEON

Product data sheet

Product profile 1.

1.1 General description

A 700 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 600 MHz band.

Table 1. **Application information**

Test signal	f	V _{DS}	PL	Gp	η_D
	(MHz)	(V)	(W)	(dB)	(%)
pulsed RF	108	50	700	23.9	73.5
CW	108	50	750	23.5	81.9

1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 600 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified ou	ıtline Graphic symbol
BLF184)	KR (SOT1214A)		
1	drain1		
2	drain2	1 2	
3	gate1		J ₅ S
4	gate2	3 4	3——5
5	source	[1]	4
			'
			2 sym117
BLF184X	KRS (SOT1214B)		
1	drain1		_
2	drain2	1 2	
3	gate1		J
4	gate2	3 4	5 3 - 5
5	source	[1]	4
			'⊢¬
			2 sym117
			·

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF184XR	-	flanged ceramic package; 2 mounting holes; 4 leads	SOT1214A
BLF184XRS	-	earless flanged ceramic package; 4 leads	SOT1214B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	135	V
V_{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

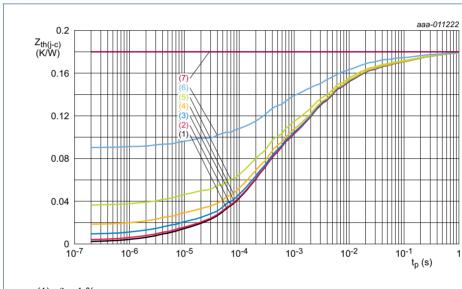
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5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T _j = 150 °C	[1][2]	0.18	K/W
Z _{th(j-c)}	transient thermal impedance from junction to case	T_j = 150 °C; t_p = 100 μs; δ = 20 %	[3]	0.065	K/W

- [1] T_i is the junction temperature.
- [2] $R_{th(j-c)}$ is measured under RF conditions.
- [3] See Figure 3.



- (1) $\delta = 1 \%$
- (2) $\delta = 2 \%$
- (3) $\delta = 5 \%$
- (4) $\delta = 10 \%$
- (5) $\delta = 20 \%$
- (6) $\delta = 50 \%$
- (7) $\delta = 100 \% (DC)$

Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

6. Characteristics

Table 6. DC characteristics

 $T_j = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.75 \text{ mA}$	135	-	-	٧
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 275 \text{ mA}$	1.25	1.9	2.25	٧
V_{GSq}	gate-source quiescent voltage	$V_{DS} = 50 \text{ V}; I_{D} = 50 \text{ mA}$	-	1.6	-	V

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Table 6. DC characteristics ...continued

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}$	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	38.5	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 9.625 A$	-	0.16	-	Ω

Table 7. AC characteristics

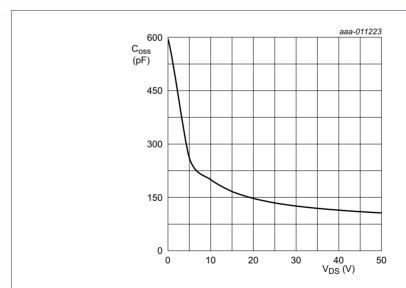
 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	3.1	-	pF
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	292	-	pF
C _{oss}	output capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	107	-	pF

Table 8. RF characteristics

Test signal: pulsed RF; t_p = 100 μ s; δ = 20 %; f = 108 MHz; RF performance at V_{DS} = 50 V; I_{Dq} = 100 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G_p	power gain	P _L = 700 W	22.8	23.9	-	dB
RLin	input return loss	P _L = 700 W	-	-20	-13	dB
η_{D}	drain efficiency	P _L = 700 W	71	73.5	-	%



 $V_{GS} = 0 V$; f = 1 MHz.

Fig 2. Output capacitance as a function of drain-source voltage; typical values per section

7. Test information

7.1 Ruggedness in class-AB operation

The BLF184XR and BLF184XRS are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions: $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$; $P_L = 700 \text{ W}$ pulsed; f = 108 MHz.

7.2 Impedance information

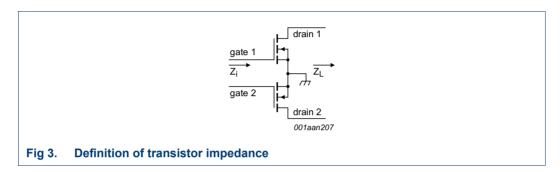


Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at V_{DS} = 50 V and P_L = 700 W.

f	Z _i	Z_L
(MHz)	(Ω)	(Ω)
108	5.8 – j19.1	5.5 + j1.0

7.3 UIS avalanche energy

Table 10. Typical avalanche data per section

 T_{amb} = 25 °C; typical test data; test jig without water cooling.

lan	E _{AS}
IAS	
(A)	(J)
15	4.3
20	2.1
25	1.3

For information see application note AN10273.

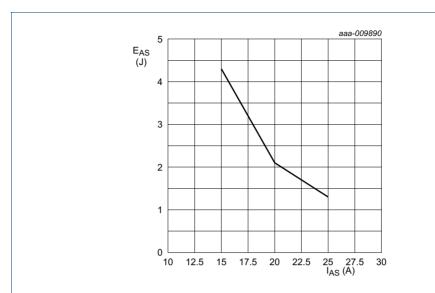


Fig 4. Non-repetitive avalanche energy as a function of single pulse avalanche current, typical values

7.4 Test circuit

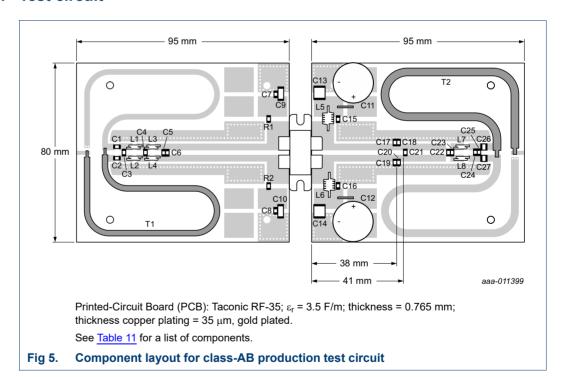


Table 11. List of components For test circuit see Figure 5.

Remarks Component Description **Value** [1] C1, C2 multilayer ceramic chip capacitor 910 pF [1] C3 multilayer ceramic chip capacitor 47 pF C4 [1] multilayer ceramic chip capacitor 51 pF

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Table 11. List of components ...continued For test circuit see Figure 5.

Component	Description	Value	Remarks
C5	multilayer ceramic chip capacitor	100 pF [1]	
C6, C23	multilayer ceramic chip capacitor	20 pF	
C7, C8, C15, C16	multilayer ceramic chip capacitor	820 pF [1]	
C9, C10, C13, C14	multilayer ceramic chip capacitor	4.7 μF, 100 V	TDK C5750X7R2A475KT
C11, C12	electrolytic capacitor	1000 μF, 63 V	
C17, C19	multilayer ceramic chip capacitor	39 pF [1]	
C18, C20	multilayer ceramic chip capacitor	27 pF [1]	
C21	multilayer ceramic chip capacitor	7.5 pF [1]	
C22	multilayer ceramic chip capacitor	22 pF [1]	
C24, C25	multilayer ceramic chip capacitor	27 pF [1]	
C26, C27	multilayer ceramic chip capacitor	1 nF [2]	
L1, L2, L3, L4	1.5 turn 0.8 mm copper wire	D = 2.8 mm	
L5, L6	5.5 turn 0.8 mm copper wire	D = 3.6 mm	
L7, L8	1 turn 1.5 mm copper wire	D = 4 mm	
R1, R2	resistor	10 Ω	SMD 1206
T1	semi rigid coax	25 Ω , length = 160 mm	Micro-Coax UT-090C-25
T2	semi rigid coax	25 Ω, length = 160 mm	Micro-Coax UT-141C-25

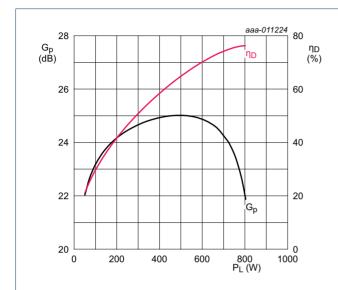
^[1] American Technical Ceramics type 800B or capacitor of same quality.

^[2] American Technical Ceramics type 100B or capacitor of same quality.

7.5 Graphical data

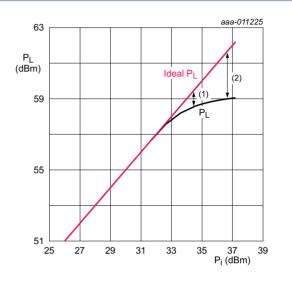
The following figures are measured in a class-AB production test circuit.

7.5.1 1-Tone CW pulsed



 V_{DS} = 50 V; I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 $\mu s;$ δ = 20 %.

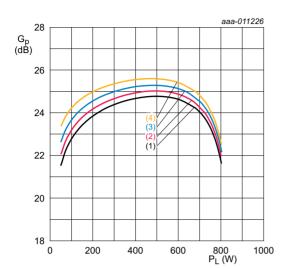
Fig 6. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 50 V; I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 $\mu s;$ δ = 20 %.

- (1) $P_{L(1dB)} = 58.6 \text{ dBm} (720 \text{ W})$
- (2) $P_{L(3dB)} = 59 \text{ dBm } (800 \text{ W})$

Fig 7. Output power as a function of input power; typical values

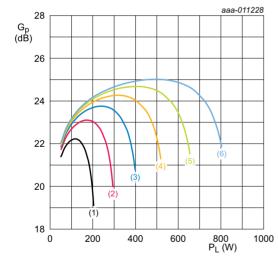


 V_{DS} = 50 V; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $I_{Dq} = 50 \text{ mA}$
- (2) $I_{Dq} = 100 \text{ mA}$
- (3) $I_{Dq} = 200 \text{ mA}$
- (4) $I_{Dq} = 400 \text{ mA}$

Fig 8. Power gain as a function of output power; typical values

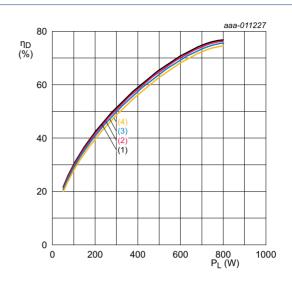




 I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $V_{DS} = 25 \text{ V}$
- (2) $V_{DS} = 30 \text{ V}$
- (3) $V_{DS} = 35 \text{ V}$
- (4) $V_{DS} = 40 \text{ V}$
- (5) $V_{DS} = 45 \text{ V}$
- (6) $V_{DS} = 50 \text{ V}$

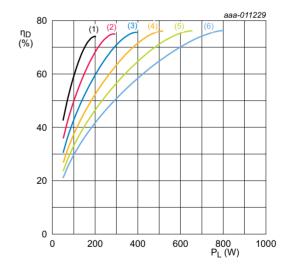
Fig 10. Power gain as a function of output power; typical values



 V_{DS} = 50 V; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $I_{Dq} = 50 \text{ mA}$
- (2) $I_{Dq} = 100 \text{ mA}$
- (3) $I_{Dq} = 200 \text{ mA}$
- (4) $I_{Dq} = 100 \text{ mA}$

Fig 9. Drain efficiency as a function of output power; typical values



 I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $V_{DS} = 25 \text{ V}$
- (2) $V_{DS} = 30 \text{ V}$
- (3) $V_{DS} = 35 \text{ V}$
- (4) $V_{DS} = 40 \text{ V}$
- (5) $V_{DS} = 45 V$
- (6) $V_{DS} = 50 \text{ V}$

Fig 11. Drain efficiency as a function of output power; typical values

8. Package outline

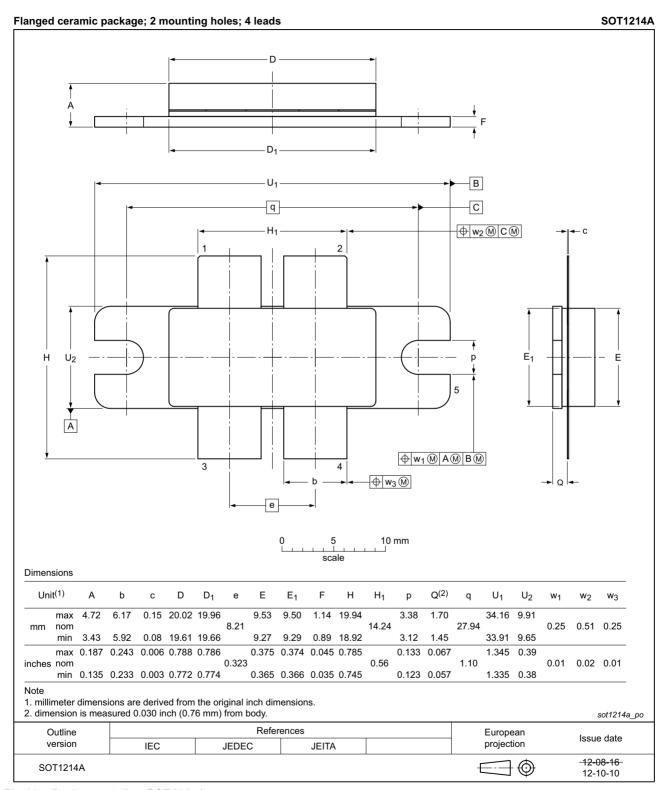


Fig 12. Package outline SOT1214A

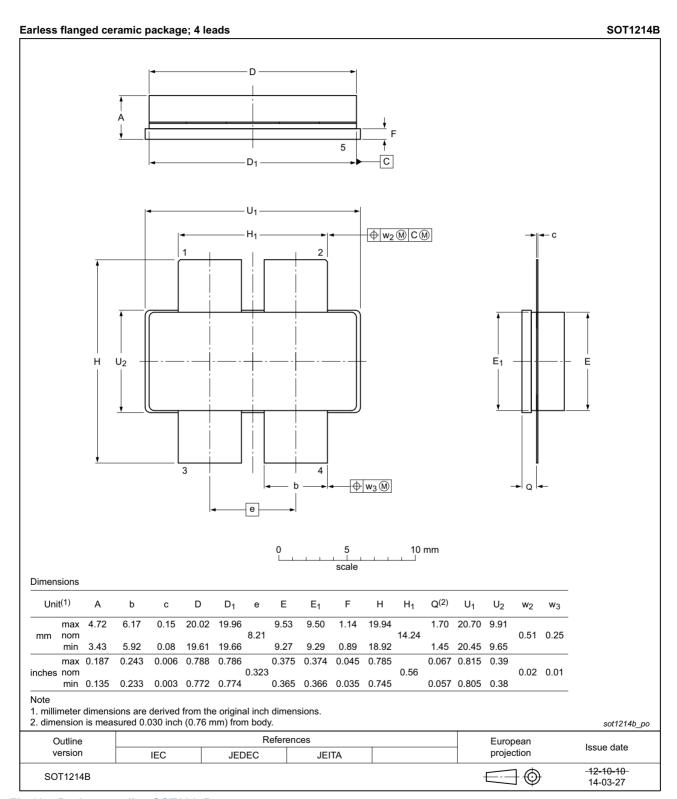


Fig 13. Package outline SOT1214B

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9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 12. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
SMD	Surface Mounted Device
UIS	Unclamped Inductive Switching
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF184XR_BLF184XRS v.4	20150901	Product data sheet	-	BLF184XR_BLF184XRS v.3	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 				
	• Legal lexis	nave been adapted to tr	ie new company na	апе мпете арргорпате.	
BLF184XR_BLF184XRS v.3	20140401	Product data sheet	-	BLF184XR_BLF184XRS v.2	
BLF184XR_BLF184XRS v.2	20140227	Preliminary data sheet	-	BLF184XR_BLF184XRS v.1	
BLF184XR_BLF184XRS v.1	20130506	Objective data sheet	-	-	

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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